

MOS FIELD EFFECT TRANSISTOR

2SK4092

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK4092 is N-channel MOS FET device that features a low gate charge and excellent switching characteristics, and designed for high voltage applications such as switching power supply, AC adapter.

FEATURES

Low on-state resistance

 $R_{DS(on)} = 0.4 \Omega MAX. (V_{GS} = 10 V, I_D = 10 A)$

Low gate charge

 Q_G = 50 nC TYP. (V_{DD} = 450 V, V_{GS} = 10 V, I_D = 21 A)

- \bullet Gate voltage rating: $\pm 30~V$
- Avalanche capability ratings

ORDERING INFORMATION

| PART NUMBER | LEAD PLATING | PACKING | PACKAGE |
|----------------|--------------|---------------|--------------------------|
| 2SK4092-A Note | Sn-Ag-Cu | 100 p/package | TO-3P (MP-88) typ. 5.0 g |

Note Pb-free (This product does not contain Pb in the external electrode and other parts.)

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

| | | 000 | |
|---|----------|-------------|----|
| Drain to Source Voltage (Vgs = 0 V) | Vdss | 600 | V |
| Gate to Source Voltage (V _{DS} = 0 V) | Vgss | ±30 | V |
| Drain Current (DC) (Tc = 25°C) | D(DC) | ±21 | Α |
| Drain Current (pulse) Note1 | D(pulse) | ±60 | Α |
| Total Power Dissipation (Tc = 25° C) | PT1 | 200 | W |
| Total Power Dissipation (T _A = 25°C) | Pt2 | 3 | W |
| Channel Temperature | Tch | 150 | °C |
| Storage Temperature | Tstg | -55 to +150 | °C |
| Single Avalanche Current Note2 | las | 21 | Α |
| Single Avalanche Energy Note2 | Eas | 29.4 | mJ |

(TO-3P)



Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 150 V, R_G = 25 $\Omega,$ V_{GS} = 20 \rightarrow 0 V

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ELECTRICAL CHARACTERISTICS (TA = 25°C)

| CHARACTERISTICS | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---|----------------------|--|------|------|------|------|
| Zero Gate Voltage Drain Current | loss | V _{DS} = 600 V, V _{GS} = 0 V | | | 10 | μA |
| Gate Leakage Current | lgss | V _{GS} = ±30 V, V _{DS} = 0 V | | | ±100 | nA |
| Gate to Source Cut-off Voltage | V _{GS(off)} | V _{DS} = 10 V, I _D = 1 mA | 2.5 | 3.0 | 3.5 | V |
| Forward Transfer Admittance Note | y _{fs} | V _{DS} = 10 V, I _D = 10 A | 4.0 | | | S |
| Drain to Source On-state Resistance ^{Note} | RDS(on) | Vgs = 10 V, Id = 10 A | | 0.34 | 0.4 | Ω |
| Input Capacitance | Ciss | V _{DS} = 10 V, | | 3240 | | pF |
| Output Capacitance | Coss | V _{GS} = 0 V, | | 550 | | pF |
| Reverse Transfer Capacitance | Crss | f = 1 MHz | | 3 | | pF |
| Turn-on Delay Time | td(on) | Vdd = 150 V, Id = 10 A, | | 38 | | ns |
| Rise Time | tr | V _{GS} = 10 V, | | 15 | | ns |
| Turn-off Delay Time | td(off) | R _G = 10 Ω | | 58 | | ns |
| Fall Time | tr | | | 12 | | ns |
| Total Gate Charge | QG | V _{DD} = 450 V, | | 50 | | nC |
| Gate to Source Charge | Q _{GS} | V _{GS} = 10 V, | | 24 | | nC |
| Gate to Drain Charge | Qgd | I _D = 21 A | | 17 | | nC |
| Body Diode Forward Voltage Note | VF(S-D) | IF = 21 A, VGS = 0 V | | 0.9 | 1.5 | V |
| Reverse Recovery Time | trr | IF = 21 A, VGS = 0 V, | | 480 | | ns |
| Reverse Recovery Charge | Qrr | di/dt = 100 A/ <i>µ</i> s | | 6000 | | nC |

Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

TEST CIRCUIT 2 SWITCHING TIME

D.U.T.

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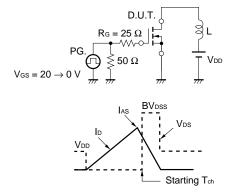
Rg

PG.

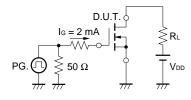
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 $\tau = 1 \,\mu s$ Duty Cycle $\leq 1\%$

Vgs

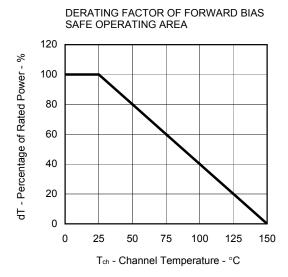


TEST CIRCUIT 3 GATE CHARGE

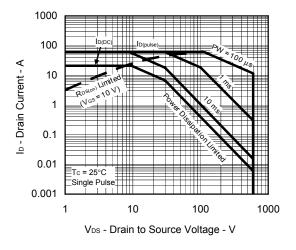


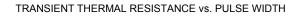
Vgs ≷R∟ 90% VGS Wave Form 0 10% VGS Vdd Vds 190% 90% VDS 10% 10% VDS Wave Form 0 td(on) tr td(off) tſ tor tof

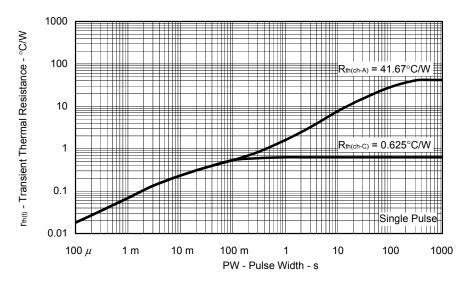
TYPICAL CHARACTERISTICS (TA = 25°C)

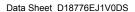


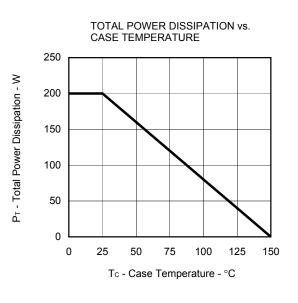
FORWARD BIAS SAFE OPERATING AREA

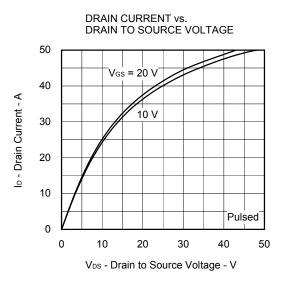




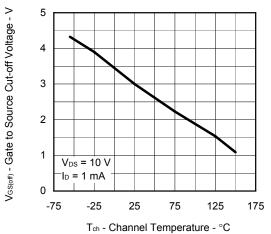




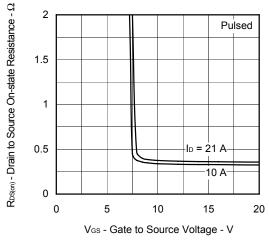




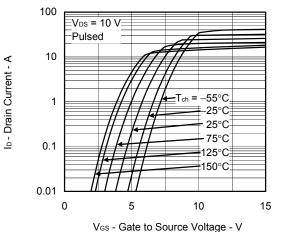




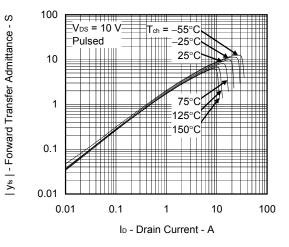




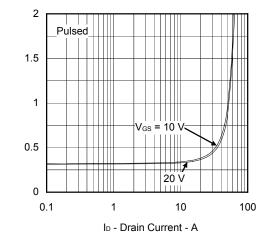
FORWARD TRANSFER CHARACTERISTICS



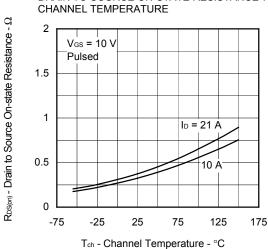
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

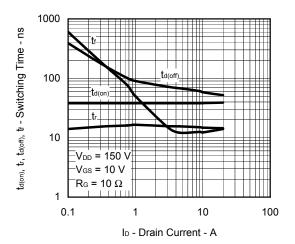


 $R_{\text{DS}(\text{on})}$ - Drain to Source On-state Resistance - Ω

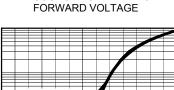


DRAIN TO SOURCE ON-STATE RESISTANCE vs.

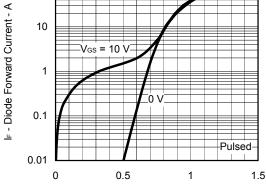




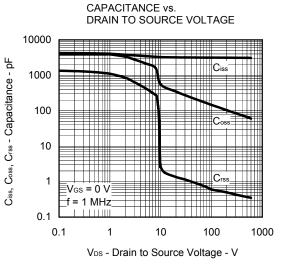




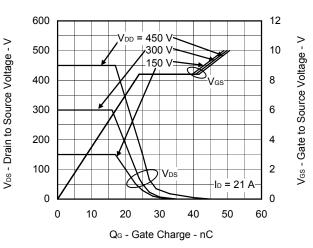
100



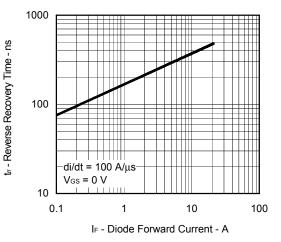
VF(S-D) - Source to Drain Voltage - V

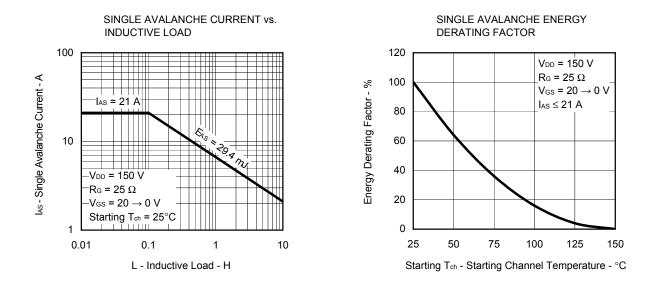


DYNAMIC INPUT/OUTPUT CHARACTERISTICS



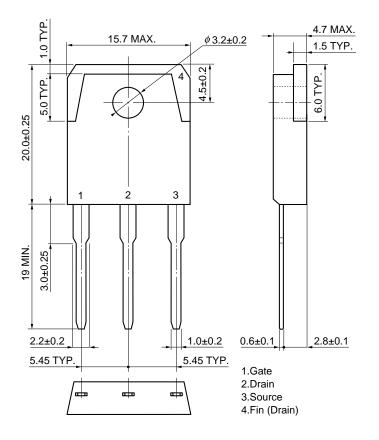
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



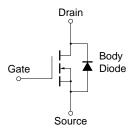


PACKAGE DRAWING (Unit: mm)

TO-3P (MP-88)



EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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